



## **SPECIFICATION**

• Supplier : Samsung electro-mechanics • Samsung P/N : CL21CR68BBANNNC

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 0.68pF, 50V, ±0.1pF, C0G, 0805

## A. Samsung Part Number

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1	Series	Samsung Multi-layer Ceramic Capacitor					
2	Size	0805 (inch co	de) L: 2.0	± 0.1 mm	W:	$1.25 \pm 0.1$	mm
3	Dielectric	C0G	8	Inner electrode		Ni	
4	Capacitance	<b>0.68</b> pF		Termination		Cu	
(5)	Capacitance	<b>±0.1</b> pF		Plating		Sn 100%	(Pb Free)
	tolerance		9	Product		Normal	
6	Rated Voltage	50 V	10	Special		Reserved for	future use
7	Thickness	$0.65 \pm 0.1$	mm ①	Packaging		Cardboard T	ype, 7" reel

## **B. Samsung Reliablility Test and Judgement condition**

	Performance	Test condition				
Capacitance	Within specified tolerance	1Mb±10% 0.5~5Vrms				
Q	413.6 min					
Insulation	10,000Mohm or 500Mohm⋅ <i>μ</i> F	Rated Voltage 60~120 sec.				
Resistance	Whichever is Smaller					
Appearance	No abnormal exterior appearance	Microscope (×10)				
Withstanding	No dielectric breakdown or	300% of the rated voltage				
Voltage	mechanical breakdown					
Temperature	COG					
Characterisitcs	(From -55 $^{\circ}$ C to 125 $^{\circ}$ C, Capacitance change shoud be within ±30PPM/ $^{\circ}$ C)					
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.				
of Termination	terminal electrode					
Bending Strength	Capacitance change :	Bending to the limit (1mm)				
	within ±5% or ±0.5pF whichever is larger	with 1.0mm/sec.				
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder				
	is to be soldered newly	245±5℃, 3±0.3sec.				
		(preheating : 80~120℃ for 10~30sec.)				
Resistance to Capacitance change :		Solder pot : 270±5℃, 10±1sec.				
Soldering heat	within ±2.5% or ±0.25pF whichever is larger					
	Tan δ, IR : initial spec.					

	Performance	Test condition				
Vibration Test	Capacitance change :	Amplitude : 1.5mm				
	within ±2.5% or ±0.25pF whichever is larger	From 10Hz to 55Hz (return : 1min.)				
	Tan δ, IR : initial spec.	2hours $\times$ 3 direction (x, y, z)				
Moisture	Capacitance change :	With rated voltage				
Resistance	within ±7.5% or ±0.75pF whichever is larger	40±2℃, 90~95%RH, 500+12/-0hrs				
	Q: 102.27 min					
	IR: 500Mohm or 25Mohm $\cdot \mu$ F					
	Whichever is Smaller					
High Temperature	Capacitance change :	With 200% of the rated voltage				
Resistance	within ±3% or ±0.3pF whichever is larger	Max. operating temperature				
	Q: 206.8 min	1000+48/-0hrs				
	IR : 1000Mohm or 50Mohm $\cdot  \mu$ F					
	Whichever is Smaller					
Temperature	Capacitance change :	1 cycle condition				
Cycling	within ±2.5% or ±0.25pF whichever is larger	Min. operating temperatur → 25 °C				
	Tan δ, IR : initial spec.	$ ightarrow$ Max. operating temperature $ ightarrow$ 25 $^{\circ}\!$				
		5 cycle test				

## C. Recommended Soldering method :

Reflow ( Reflow Peak Temperature : 260+0/-5  $^{\circ}$ C, 10sec. Max )

<sup>\*</sup> For the more detail Specification, Please refer to the Samsung MLCC catalogue.